International Journal of Engineering and Science Invention

e-ISSN: 2319 – 6734 p-ISSN: 2319 – 6726

CERTIFICATE

It is certify that the paper entitled by "Electrons in Duane-Hunt Law and Drift in Semiconductors" has been published in International Journal of Engineering and Science Invention (IJESI).

Your article has been published with following details:

Author's Name:	*Ravi Kumar Chanana*
Journal Name:	*International Journal of Engineering and Science Invention (IJESI)*
Journal Web:	*www.ijesi.org*
Journal Type:	*Online & Offline*
Review Type:	*Peer Review Refereed*
Publication Year:	*2026*
Publication Month:	*November*
Vol No.:	*15*
Issue No.:	*11*

Editor-In-Chief
International Journal of Engineering and Science Invention (IJESI)
E-mail ID: ijesi@invmails.com
Web: www.ijesi.org

Impact Factor : 5.96

UGC Approval Serial Number: 2573 & UGC Journal Number: 43302